



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	60	V
Collector-Emitter Voltage	V _{CEO}	25	V
Emitter-Base Voltage	V_{EBO}	7	V
Continuous Collector Current	Ic	7	A
Peak Pulse Current	I _{CM}	20	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)		3.0 24	W	
Linear Derating Factor	(Note 6)	P _D	1.6 12.8	mW/°C	
Thermal Begintenes, Junction to Ambient	(Note 5)	$R_{ heta JA}$	42		
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{ heta JA}$	78	°C/W	
Thermal Resistance, Junction to Lead	(Note 7)	$R_{ heta JL}$	8.8	1	
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C	

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

^{5.} For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.

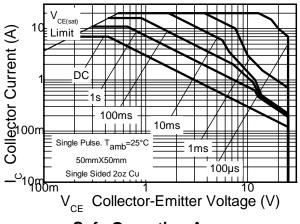
6. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.

7. Thermal resistance from junction to solder-point (at the end of the collector lead).

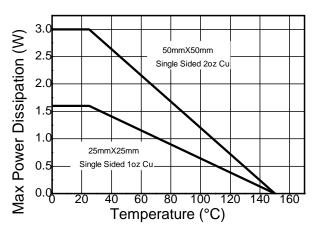
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



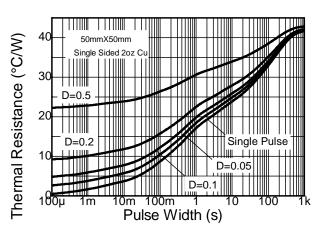
Thermal Characteristics and Derating Information



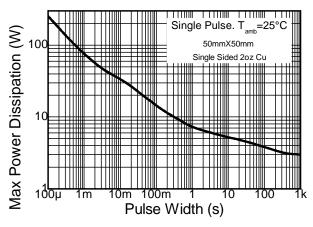
Safe Operating Area



Derating Curve



Transient Thermal Impedance



Pulse Power Dissipation





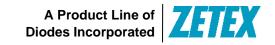
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	60	120	-	V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage	BV_{CER}	60	120	_	V	$I_C = 1\mu A$, RB $\leq 1k\Omega$
Collector-Emitter Breakdown Voltage (Note 9)	BV_{CEO}	25	35	_	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7.0	8.1	_	V	I _E = 100μA
Collector Cut-Off Current	I _{CBO}	_	< 1	50 0.5	nΑ μΑ	V _{CB} = 50V V _{CB} = 50V, T _A = +100°C
Collector Cut-Off Current	I _{CER} R≤1kΩ		< 1 —	100 0.5	nA	V _{CB} = 50V, T _A = +100°C V _{CB} = 50V, T _A = +100°C
Emitter Cut-Off Current	I _{EBO}	_	< 1	10	nA	V _{EB} = 6V
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(sat)}	_	28 35 55 115 195	40 50 75 140 230	mV	I_C = 500mA, I_B = 10mA I_C = 1A, I_B = 100mA I_C = 1A, I_B = 10mA I_C = 2A, I_B = 10mA I_C = 6.5A, I_B = 150mA
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	_	980	1080	mV	I _C = 6.5A, I _B = 150mA
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	_	890	980	mV	I _C = 6.5A, V _{CE} = 1V
DC Current Gain (Note 9)	h _{FE}	300 300 200 40	400 450 275 55	_	_	$I_C = 10\text{mA}, V_{CE} = 1\text{V}$ $I_C = 1\text{A}, V_{CE} = 1\text{V}$ $I_C = 7\text{A}, V_{CE} = 1\text{V}$ $I_C = 20\text{A}, V_{CE} = 1\text{V}$
Transition Frequency	f⊤	_	150	_	MHz	V _{CE} = 10V, I _C = 100mA, f = 50MHz
Output Capacitance (Note 9)	C _{obo}		48		pF	V _{CB} = 10V, f = 1MHz
Switching Times	t _{ON}	_	33 464	<u> </u>	ns	V _{CC} = 10V, I _C = 1A, I _{B1} = -I _{B2} = 100mA

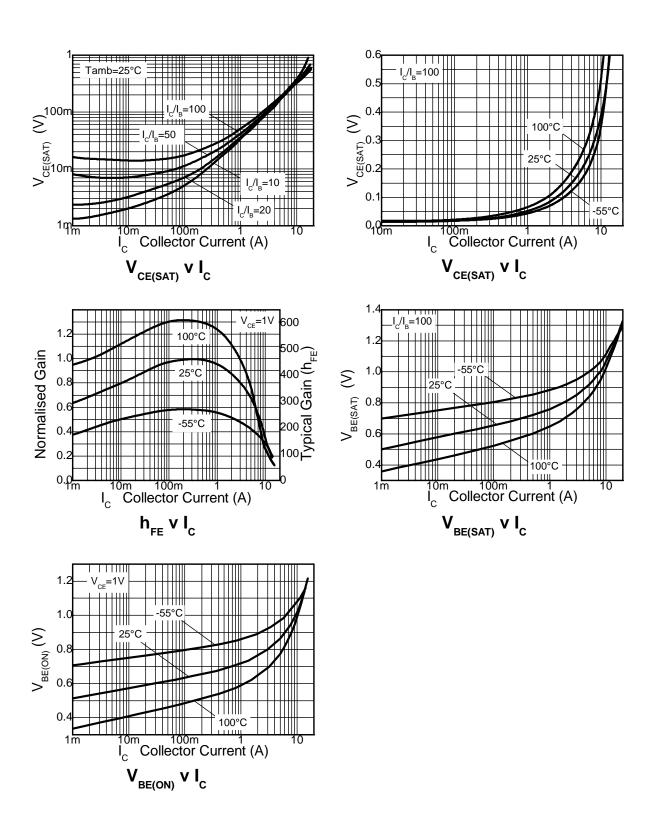
Note:

9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

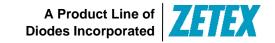




Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

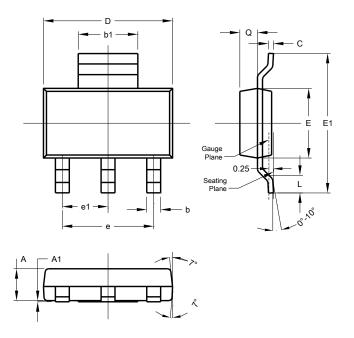






Package Outline Dimensions

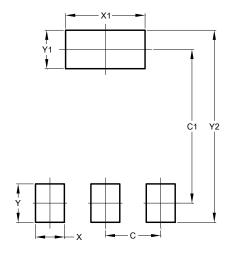
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

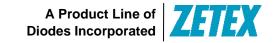
Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
C2	8.00





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